Notice of Allowability	Application No.	Applicant(s)	
	10/617,683	LEE, SANG-DON	
	Examiner	Art Unit	
	Luan Thai	2829	
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The MAILING DATE of this communication appeal All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RID of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in this apport or other appropriate communication GHTS. This application is subject to	olication. If not include will be mailed in due	ed course. THIS
1. This communication is responsive to			
2. The allowed claim(s) is/are 1-18 (renumbered as 1-2, 11, 1	3-16, 12, 17, 3-10 and 18, respectiv	ely).	
3. The drawings filed on 14 July 2003 are accepted by the Ex	aminer.		
4. Acknowledgment is made of a claim for foreign priority ur	nder 35 U.S.C. § 119(a)-(d) or (f).		
a) ⊠ All b) □ Some* c) □ None of the:			•
1. Certified copies of the priority documents have been received.			
2. Certified copies of the priority documents have been received in Application No			
3. Copies of the certified copies of the priority documents have been received in this national stage application from the			
International Bureau (PCT Rule 17.2(a)).	· · · ·	•	
* Certified copies not received:	mercury and space in the little in the		•
Applicant has THREE MONTHS FROM THE "MAILING DATE" of this communication to file a reply complying with the requirements noted below. Failure to timely comply will result in ABANDONMENT of this application.			
5. A SUBSTITUTE OATH OR DECLARATION must be submitted. Note the attached EXAMINER'S AMENDMENT or NOTICE OF INFORMAL PATENT APPLICATION (PTO-152) which gives reason(s) why the oath or declaration is deficient.			
6. CORRECTED DRAWINGS (as "replacement sheets") mus	t be submitted.		
(a) ☐ including changes required by the Notice of Draftsperson's Patent Drawing Review (PTO-948) attached			
1) hereto or 2) to Paper No./Mail Date	•		
(b) including changes required by the attached Examiner's Paper No./Mail Date	s Amendment / Comment or in the O	office action of	
Identifying indicia such as the application number (see 37 CFR 1 each sheet. Replacement sheet(s) should be labeled as such in t			back) of
7. DEPOSIT OF and/or INFORMATION about the deposit attached Examiner's comment regarding REQUIREMENT			Note the
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	Control Application of the Control o	•	
Attachment(s)	the state of the s	•	
1. Notice of References Cited (PTO-892)	5. Notice of Informal P	atent Application (PT	D-152)
2. Notice of Draftperson's Patent Drawing Review (PTO-948)	6. Interview Summary	(PTO-413),	
3. Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date 7/14/03	Paper No./Mail Dat 8), 7. ☐ Examiner's Amenda		
4. Examiner's Comment Regarding Requirement for Deposit	8. X Examiner's Stateme	nt of Reasons for Allo	wance
of Biological Material Whoulum	9.		
LUANTHAI , ,			
PRIMARY EXAMINER 9/17/04			

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DETAILED ACTION

1. Claims 1-18 are allowed and renumbered as 1-2, 11, 13-16, 12, 17, 3-10 and 18, respectively.

2. The following is an examiner's statement of reasons for allowance:

The cited art taken either singly or in combination with other prior arts fails to anticipate or fairly suggest the claimed limitations in independent claims 1 and 18 in a manner which would warrant a rejection under 35 U.S.C. § 102 or 35 U.S.C. § 103, especially when these limitations are considered within the specific combination claimed.

The cited art, U.S. Pat. No. 6,689,664 to Park, discloses a method for fabricating a semiconductor transistor but it fails to teach or fairly suggest, among others, at least the method steps of: forming a first trench by selectively etching the first oxide layer, the first nitride layer and a first portion of the substrate; firming a second trench defining a channel region therebeneath by selectively etching the first oxide layer, the first nitride layer and a second portion of the substrate; forming a gate oxide layer on lateral sides and a bottom side of the second trench, especially when these steps are considered within the specific combination claimed.

3. Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably

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accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

4. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Luan Thai whose telephone number is 571-272-1935. The examiner can normally be reached on 6:45 AM - 4:15 PM, Monday to Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Michael Tokar can be reached on 571-272-1812. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Luan Thai

Primary Examiner Art Unit 2829 September 17, 2004